DECLARATI N AND P WER FATTORNEY

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name: that I verily believe I am the original, first and sole inventor (if only one name is listed below) or a joint inventor (if plural names are listed below) of the subject matter claimed and for which a patent is sought in the application entitled:

NONVOLATILE SEMICONDUCTOR MEMORY DEVICE CAPABLE OF ACCURATELY AND QUICKLY ADJUSTING STEP-UP VOLTAGE

which application is: the attached application (for original application)	☐ application	☐ application Serial No			
yer engine approximation,			, are		
that I have reviewed and understar the claims, as amended by any ame which I am aware and which is ma- claim foreign priority benefits under patent or inventor's certificate listed inventor's certificate on this invention	ndment referred to a terial to the examina r Title 35, United St l below and have al	le specification on the second that I acknown that I acknown the second	nowledge my dulication under 37 (§172 or §365 of al said list any forei	tified application, including ty to disclose information of C.F.R. 1.56; and that I hereby ny foreign application(s) for ign application for patent or	
Application Number	Country	Filing Date		Priority Claimed	
2003-008088	Japan	January 1	6, 2003	(yes or no)	
I hereby claim the benefit of Title 35, United States Code §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in a listed prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge my duty to disclose any material information under 37 C.F.R. 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:					
Application Serial No.	Filing	Date		Status	
			(patente	ed, pending, abandoned)	
I hereby appoint John H. Mion, Reg. Robert J. Seas, Jr., Reg. No. 21,092; Reg.No. 24,513; J. Frank Osha, Reg. 19,093; Louis Gubinsky, Reg. No. 24 Inge, Reg. No. 26,916; Joseph J. Ruc Reg. No. 29,710; Howard L. Bernstei 31,333; Gordon Kt, Reg. No. 30,764; Reg. No. 32,197; William H. Mandir 32,778; and Abraham J. Rosner, Reg. the Patent and Trademark Office of addressed to SUGHRUE, MION, ZIN	Darryl Mexic, Reg. No. 24,625; Waddel ,835; Neil B. Siegel, h, Jr., Reg. No. 26,55, n, Reg. No. 25,665; Assan J. Mack, Reg. Reg. No. 32,156; Son Signal Sign	No. 23,063; Robel A. Biggart, Reg Reg. No. 25,200 7; Sheldon I. Ladan J. Kasper, Ro No. 30,951; Frant cott M. Daniels, neys to prosecute 1, and request al AS, 2100 Pennsyl	ert V. Sloan, Reg. J. No. 24,861; Rob J. David J. Cushir ndsman, Reg. No eg. No. 25,426; Ke k L. Bernstein, Re Reg. No. 32,562; e this appliation and ll correspondence lvania Avenue, N.	No. 22,775; Peter D. Olexy, pert G. McMorrow, Reg. No. 19, 703; John R. D. 25,430; Richard C. Turner, enneth J. Burchfiel, Reg. No. 19, 1484; Mark Boland, Brian W. Hannon, Reg. No. 19 to transact all business in the about the application be W., Washington, D.C. 20037.	
I hereby declare that all statements information and belief are believed to willful false statements and the like Title 18 of the United States Code are or any patent issuing thereon.	o be true; and furth so made are punish	er that these stat able by fine or in	tements were mad nprisonment, or l	de with the knowledge that both, under Section 1001 of	
Date December 12, 2003	First Inventor S	HUNYA		SHIMASAKI	
Residence Kanagawa, Japan	First !		Middle Initial I	馬 Last Name 奇	
	Post Office Address 0	O NEC Mic	ro Systems	• Ltd. • 403-53.	
Citizenship	Kosugimachi_	l-chome, N	akahara-ku	Kawasaki-shi,	
				Kanagawa, Japan	
Date	Second Inventor	t Name	Middle Initial	Last Name	
Residence	Signature			Dan (400)	
	Post Office Address				

Citizenship___